# GSR811 Reset IC

### **Product Description**

The GSR811 is microprocessor ( $\mu$ P) supervisory circuit used to monitor the power supplies in  $\mu$ P and digital systems. It provides excellent circuit reliability and low cost by eliminating external components and adjustments when used with +5V, +3.3V, +3.0V, or 2.5V powered circuits. GSR811 also provide a debounced manual reset input.

The circuit perform a single function: it asserts a reset signal whenever the  $V_{CC}$  supply voltage declines below a preset threshold, keeping it asserted for at least 140ms after  $V_{CC}$  has risen above the reset threshold. Reset thresholds suitable for operation with a variety of supply voltages are available.

The GSR811 has push-pull output and has an

active-low **RESET** output. The reset comparator is designed to ignore fast transients on V<sub>CC</sub>, and the output is guaranteed to be in the correct logic state for V<sub>CC</sub> down to 1.2V within the range of the operating temperature .

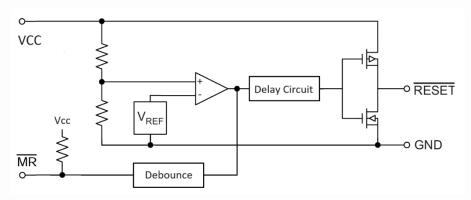
### **Features**

- Manual Reset Available
- Precision monitoring of Supply Voltages
  Available Threshold Options:
  - 4.63V (GSR811L)
  - 4.38V (GSR811M)
  - 4.00V (GSR811J)
  - 3.08V (GSR811T)
  - 2.93V (GSR811S)
  - 2.63V (GSR811R)
  - 2.32V (GSR811Z)
  - 140ms Minimum Reset Pulse Width
- Push-Pull Configurations for RESET Output
- 10µA Supply Current Typically
- Power Supply Transient Immunity
- RoHS Compliant

### **Applications**

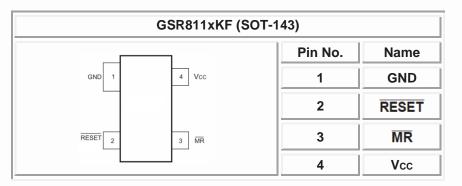
- Computers
- Controllers
- Intelligent Instruments
- Embedded Control Systems
- Battery-powered Equipment

### **Block Diagram**





### Packages & Pin Assignments



## **Pin Description**

Name	Туре	Description		
GND	-	Ground Pin.		
RESET	0	Active-Low Reset Output (Push-Pull). RESET Output remains low while VCC is below the reset threshold or while MR is held low, and for at least 140ms after the reset conditions are terminated.		
MR	I	Manual Reset Input. A logic low on $\overline{MR}$ asserts reset. Reset remains asserted as long as $\overline{MR}$ is low and for 140ms after $\overline{MR}$ returns high. This active-low input has an internal 20k $\Omega$ pull-up resistor. It can be driven from a TTL or CMOS-logic line, or shorted to ground with a switch. Leave open if unused.		
Vcc	I	Supply Voltage.		

### **Ordering and Marking Information**

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GS P/N	Package	Marking	Reset Threshold
*GSR811LKF	SOT-143	AMAA	4.63V
*GSR811MKF	SOT-143	ANAA	4.38V
*GSR811JKF	SOT-143	AOAA	4.00V
GSR811TKF	SOT-143	APAA	3.08V
GSR811SKF	SOT-143	AQAA	2.93V
GSR811RKF	SOT-143	ARAA	2.63V
*GSR811ZKF	SOT-143	AZAZ	2.32V

★ Please contact a GS sales representative to inquire about production status.



Symbol	Parameter	Value	Unit	
Vcc	Supply Voltage	-0.3 to +6.0	V	
	All Other Inputs	-0.3 to Vcc+0.3	V	
Іоυт	Output Current	20	mA	
T <sub>J(MAX)</sub>	Maximum Junction Temperature	150	0 °C	
Tstg	Storage Temperature Range	-65 to +150	°C	
Reja	Junction-to-ambient thermal resistance 300		°C/W	
PD	Power Dissipation 320		mW	
T <sub>SOD</sub>	Lead temperature (Soldering, 10 s)	300 °C		
	Human-body model (HBM)	2000	V	
VESD	Charged-device model (CDM)	200	V	

### Absolute Maximum Ratings

Note: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **Recommended Operating Conditions**

Symbol	Parameter	Value	Unit
T <sub>A</sub>	Operating Temperature Range	-40 to +85	٥C

### **Electrical Characteristics**

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Over operating free-air temperature range (unless otherwise noted) (Note 1)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	Operating Voltage	Ta=0°C ~ +70°C	1.0	-	5.5	V
Vcc	Range	Ta=-40°C ∼ +85°C	1.2	-	5.5	
lcc	Supply Current	V <sub>CC</sub> =5.5V, GSR811(L/M/J)	-	10	25	μA
	(Ta=-40°C ~ +85°C)	Vcc=3.6V, GSR811(T/S/R/Z)	-	8	25	μA
Vтн	GSR811L	T <sub>A</sub> =25°C	4.54	4.63	4.72	V
	Reset Threshold Voltage	T <sub>A</sub> =-40 to 85°C	4.50	-	4.75	
	GSR811M	T <sub>A</sub> =25°C	4.29	4.38	4.47	
	Reset Threshold Voltage	T <sub>A</sub> =-40 to 85°C	4.25	-	4.50	V
	GSR811J	T <sub>A</sub> =25°C	3.92	4.00	4.08	v
	Reset Threshold Voltage	T <sub>A</sub> =-40 to 85°C	3.89	-	4.10	

# **Electrical Characteristics (Continued)**

	GSR811T	T <sub>A</sub> =25°C	3.01	3.08	3.15	V	
	Reset Threshold Voltage	T <sub>A</sub> =-40 to 85°C	3.00	-	3.17	V	
	GSR811S	T <sub>A</sub> =25°C	2.86	2.93	3.00		
	Reset Threshold Voltage	T <sub>A</sub> =-40 to 85°C	2.85	-	3.01	V	
Vтн	GSR811R	T <sub>A</sub> =25°C	2.56	2.63	2.69		
	Reset Threshold Voltage	T <sub>A</sub> =-40 to 85°C	2.55	-	2.70	V	
	GSR811Z	T <sub>A</sub> =25⁰C	2.26	2.32	2.37		
	Reset Threshold Voltage	T <sub>A</sub> =-40 to 85°C	2.25	-	2.38	V	
-	Reset Threshold Temp Coefficient			30		ppm/ºC	
	GSR811(L/M/J)	N/ 405 N/		4.0			
	Vcc to Reset Delay	Vod=125mV		40			
-	GSR811(T/S/R/Z)					μs	
	Vcc to Reset Delay	Vod=125mV		20			
<b>t</b> RS	Reset Active Timeout Period	T <sub>A</sub> =-40 to 85°C	140	240	560	ms	
<b>t</b> MR	MR Minimum Pulse Width		10			μs	
	MR Glitch Immunity			100		ns	
<b>t</b> MD	MR to Reset Propagation Delay			0.5		μs	
Vih	GSR811(L/M/J)		2.3				
Vil	MR Input Threshold	Vcc > Vтн (max)			0.8	V	
Vін	GSR811(L/M/J)		0.8xVcc				
VIL	MR Input Threshold	Vcc > Vтн (max)			0.25xVcc	V	
	MR Pull Up Resistance		10	20	30	kΩ	
	GSR811(T/S/R/Z)	Vcc > Vтн (max),					
	Output High Voltage	ISOURCE = $800\mu$ A	V <sub>cc</sub> -1.5	-	-	V	
Vон	GSR811(T/S/R/Z)	Vcc > Vтн (max),					
	Output High Voltage	ISOURCE = $500\mu$ A	0.8xVcc	-	-		
	GSR811(L/M/J)	Vcc = Vтн (min),					
	Output Low Voltage	ISINK = $3.2\text{mA}$	•	-	0.4		
Vol	GSR811(T/S/R/Z)	VCC = VTH (min), ISOURCE = 1.2mA		-	0.3	V	
	Output Low Voltage	1300R0E = 1.2111A					

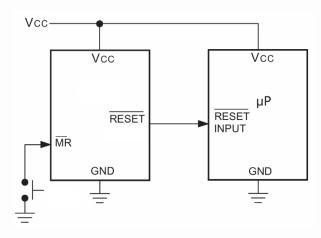
Note 1: Production testing done at  $T_A = 25^{\circ}C$ , over temperature limits specified by design only.

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### **Application Information**

### **Typical Application Circuit**

The GSR811 is a supervisor circuit for microprocessor and digital systems.





#### **Negative-Going Vcc Transients**

GSR811 is relatively immune to short negative-going transients or glitches on Vcc. Figure 2 shows the maximum pulse width a negative-going Vcc transient can have without causing a reset pulse. In general, as the magnitude of the transient increases, going further below the threshold, the maximum allowable pulse width decreases. Typically, for the 4.63V and 4.38V version of the GSR811, a Vcc transient that goes 100 mV below the reset threshold and lasts 20  $\mu$ s or less will not cause a reset pulse. A 0.1 $\mu$ F bypass capacitor mounted as close as possible to the Vcc pin will provide additional transient rejection.

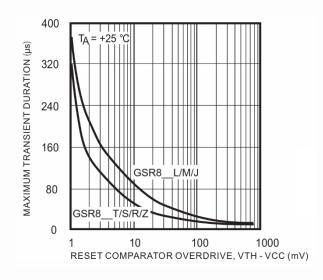


Figure. 2

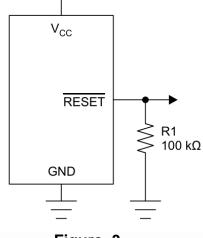
#### Ensuring a Valid Reset Output Down to Vcc = 0 V

When Vcc falls below 1.2V, the GSR811  $\overline{\text{RESET}}$  output no longer sinks current—it becomes an open circuit. Therefore, high-impedance CMOS logic inputs connected to  $\overline{\text{RESET}}$  can drift to undetermined voltages. This presents no problem in most applications since most  $\mu$ P and other circuitry is inoperative with Vcc below 1.2V.



However, in applications where **RESET** must be valid down to 0V, adding a pull-down resistor to **RESET** causes any stray leakage currents to flow to ground, holding **RESET** low (Figure 3).

R1's value is not critical;  $100k\Omega$  is large enough not to load  $\overline{\text{RESET}}$  and small enough to pull  $\overline{\text{RESET}}$  to ground.





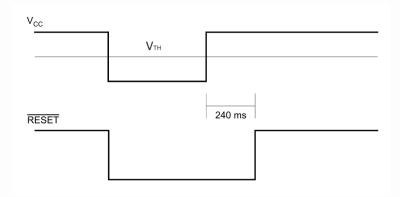
### **Manual Reset Input**

Many  $\mu$ P-based products require manual reset capability, allowing the operator, a test technician, or external logic circuitry to initiate a reset. A logic low on  $\overline{MR}$  asserts reset. Reset remains asserted while  $\overline{MR}$  is low, and for the Reset Active Timeout Period (t<sub>RS</sub>) after  $\overline{MR}$  returns high. This input has an internal 20k $\Omega$  pull-up resistor, so it can be left open if it is not used.  $\overline{MR}$  can be driven with TTL or CMOS-logic levels, or with open drain/collector outputs. Connect a normally open momentary switch from  $\overline{MR}$  to GND to create a manual reset function; external debounce circuitry is not required. If  $\overline{MR}$  is driven from long cables or if the device is used in a noisy environment, connecting a 0.1 $\mu$ F capacitor from  $\overline{MR}$  to ground provides additional noise immunity.

#### **Reference of Reset Curve**

When Vcc supply voltage declines below the reset threshold, the active-low RESET output is Low.

When the Vcc supply voltage rises above the reset threshold, the active-low **RESET** output rises High after 240 ms typically.

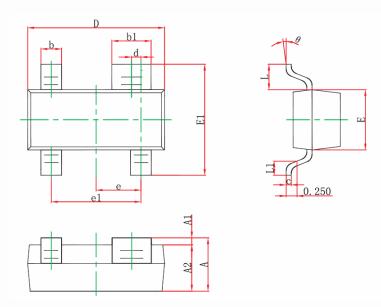






# Package Dimension

GLOBALTECH SEMICONDUCTOR SOT-143



	Dimensions				
	Millimeters		Inches		
SYMBOL	MIN	MAX	MIN	MAX	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035 0.041		
b	0.300	0.500	0.012 0.020		
b1	0.750	0.900	0.030 0.035		
С	0.080	0.150	0.003 0.006		
D	2.800	3.000	0.110	0.118	
d	0.200 (TYP) 0.008 (TYP)			TYP)	
Е	1.200	1.400	0.047 0.055		
E1	2.250	2.550	0.089	0.100	
е	0.950 (TYP) 0.037 (TYP)			TYP)	
e1	1.800	2.000	0.071 0.079		
L	0.550 (REF) 0.022 (REF)			REF)	
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

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# **CONTACT US**

GS Headquarter				
	4F.,No.43-1,Lane11,Sec.6,Minquan E.Rd Neihu District Taipei City 114, Taiwan (R.O.C)			
G	886-2-2657-9980			
Q•	886-2-2657-3630			
@	sales_twn@gs-power.com			

Wu-Xi Branch					
	No.21 Changjiang Rd., WND, Wuxi, Jiangsu, China (INFO. &. TECH. Science Park Building A 210 Room)				
Fo	86-510-85217051				
Q	86-510-85211238				
e	sales_cn@gs-power.com				

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